

**Antiferromagnetic Molecular Metal (Me-3,5-DIP)[Ni(dmit)<sub>2</sub>]<sub>2</sub> (Me-3,5-DIP = N-methyl-3,5-diiodopyridinium; dmit = 1,3-dithiole-2-thione-4,5-dithiolate)**  
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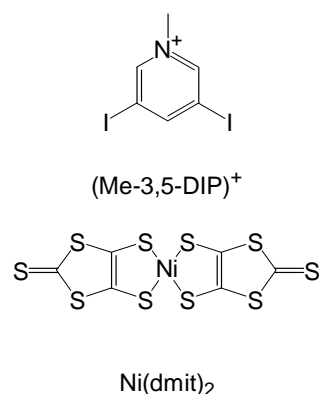
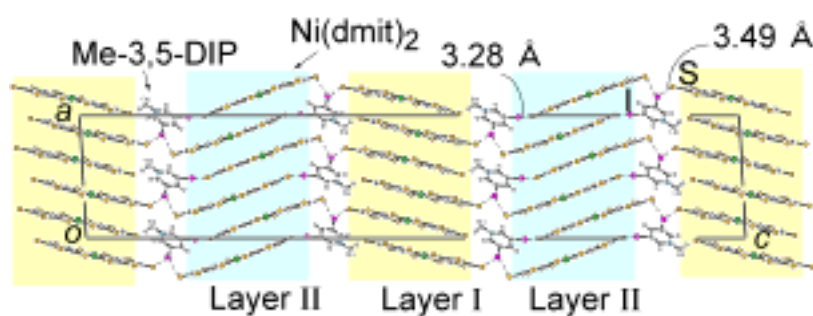
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We have succeeded in the preparation of a new antiferromagnetic molecular metal (Me-3,5-DIP)[Ni(dmit)<sub>2</sub>]<sub>2</sub>. The crystal consists of two crystallographically independent layers, which are alternatively arranged along the *c*-axis (Layers I and II). In Layer I, Ni(dmit)<sub>2</sub> anions form strongly dimerized columns. In Layer II, on the other hand, the anion arrangement is similar to so-called the ‘spanning-overlap’ packing as seen in  $\alpha$ -Et<sub>2</sub>Me<sub>2</sub>N[Ni(dmit)<sub>2</sub>]<sub>2</sub>,<sup>1</sup> but slightly different in the anion orientation. These uncommon structural features are considered to be furnished by the short cation-anion interactions (I⋯S). Tight-binding band calculations suggest that this material has two contrastive characters: Mott-insulating state (Layer I) and two-dimensional metallic conduction in the *ab* plane (Layer II).

Temperature dependence of electrical resistivity depends strongly on current directions. For the *a*-axis directions, the resistivity decreases monotonically with lowering temperature. The *b*-axis resistivity is also metallic but it is accompanied by a broad maximum at around 72 K. In contrast, for the interlayer direction (*//c*), the resistivity at room temperature is about two orders of magnitude larger than those for the other directions and increases with lowering temperature down to 100 K. Magnetic susceptibility  $\chi$  shows Currie-Weiss-like temperature dependence in a range of 20-300 K. The  $\chi$  behavior would be explained by the superposition of the contribution from the localized spins in Layer I and the Pauli paramagnetism of conduction electrons in Layer II. In fact, the  $\chi$ -*T* curve can be fitted by the Bonner-Fisher model<sup>2</sup> (The Hamiltonian is defined as  $H = -2J \sum_i (\hat{S}_i \cdot \hat{S}_{i+1})$ ;  $J/k_B = -16.8$  K) with an additional constant term down to 10 K. At 10 K,  $\chi$  has an anomaly and becomes anisotropic below this temperature. This is the evidence for the antiferromagnetic transition. In this material, both conduction and magnetism are based only on  $\pi$  electrons of Ni(dmit)<sub>2</sub>.



Reference

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2. (a) Bonner, J. C.; Fisher, M. E. *Phys. Rev. A* **1964**, 135 (3A), A640. (b) Hatfield, W. E.; Weller, R. R.; Hall, J. W. *Inorg. Chem.* **1980**, 19, 3825.